

# TN05N60SC

#### N-Channel Enhancement Mode Power MOSFET

#### **Features**

● V<sub>DS</sub>=60V,I<sub>D</sub>=5A

 $R_{DS(ON)}$  <35m $\Omega$  @  $V_{GS}$ =10V (Typ.26m $\Omega$ )

 $R_{DS(ON)}$  <45m $\Omega$  @  $V_{GS}$ =4.5V (Typ.32m $\Omega$ )

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

# Application

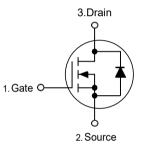
- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

# 3

SOT-23-3

1. Gate 2. Source 3. Drain

## **Schematic Diagram**



## **Absolute Maximum Ratings**

Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter  | ymbol               | Limit      | Unit |
|--|---------------------|------------|------|
| Drain-Source Voltage                             | V <sub>DS</sub>     | 60         | V    |
| Gate-Source Voltage                              | V <sub>G</sub> S    | ±20        | V    |
| Drain Current-Continuous                         | I <sub>D</sub>      | 5          | Α    |
| Drain Current-Continuous(T <sub>C</sub> =100 °C) | <sub>D</sub> (100℃) | 3.         | Α    |
| Pulsed Drain Current                             | I <sub>DM</sub>     | 24         | А    |
| Maximum Power Dissipation                        | P <sub>D</sub>      | 2          | W    |
| Operating Junction and Storage Temperature Range | $T_{J}, T_{STG}$    | -55 To 150 | °C   |

#### **Thermal Characteristics**

| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 62.5 | °C/W |
|--|-----------------|------|------|
|--|-----------------|------|------|

## **Electrical Characteristics**

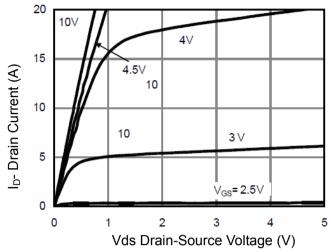
(Ta=25°C unless otherwise specified)

| Parameter                          | Symbol              | Condition  | Min           | Тур        | Max        | Unit     |
|------------------------------------|---------------------|--|---------------|------------|------------|----------|
| Off Characteristics                | •                   |  |               |            |            |          |
| Drain-Source Breakdown Voltage     | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250μA                        | 60            | -          | -          | V        |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>    | V <sub>DS</sub> =60V,V <sub>GS</sub> =0V                         |               | -          | 1          | μA       |
| Gate-Body Leakage Current          | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V                        |               | -          | ±100       | nA       |
| On Characteristics (Note 3)        | •                   |  |               |            |            |          |
| Gate Threshold Voltage             | $V_{GS(th)}$        | $V_{DS}=V_{GS}$ , $I_{D}=250\mu A$                               | 1.2           | 1.6        | 2.5        | V        |
| Drain-Source On-State Resistance   | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =5A                         | -             | 26         | 35         | mΩ       |
|                                    | R <sub>DS(ON)</sub> | V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A                        | -             | 32         | 45         | mΩ       |
| Forward Transconductance           | <b>g</b> FS         | V <sub>DS</sub> =5V,I <sub>D</sub> =5A                           |               | -          | -          | S        |
| Dynamic Characteristics (Note4)    | •                   |  |               |            |            |          |
| Input Capacitance                  | C <sub>lss</sub>    | V <sub>DS</sub> =30V,V <sub>GS</sub> =0V,<br>F=1.0MHz            | -             | 979        | -          | PF       |
| Output Capacitance                 | C <sub>oss</sub>    |  | -             | 120        | -          | PF       |
| Reverse Transfer Capacitance       | C <sub>rss</sub>    |  | -             | 100        | -          | PF       |
| Switching Characteristics (Note 4) | •                   |  |               |            |            |          |
| Turn-on Delay Time                 | t <sub>d(on)</sub>  |  | -             | 5.2        | -          | nS       |
| Turn-on Rise Time                  | t <sub>r</sub>      | $V_{DD}$ =30V, $R_L$ =6.7 $\Omega$                               | -             | 3          | -          | nS       |
| Turn-Off Delay Time                | t <sub>d(off)</sub> | $V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$                           | -             | 17         | -          | nS       |
| Turn-Off Fall Time                 | t <sub>f</sub>      |  | -             | 2.5        | -          | nS       |
| Total Gate Charge                  | Qg                  | V <sub>DS</sub> =30V,I <sub>D</sub> =5A,<br>V <sub>GS</sub> =10V | -             | 22         |            | nC       |
| Gate-Source Charge                 | $Q_{gs}$            |  | -             | 3.3        |            | nC       |
| Gate-Drain Charge                  | $Q_{gd}$            |  | -             | 5.2        |            | nC       |
| Drain-Source Diode Characteristics | <u> </u>            |  | •             | •          |            | •        |
| Diode Forward Voltage (Note 3)     | V <sub>SD</sub>     | V <sub>GS</sub> =0V,I <sub>S</sub> =5A                           |               |            | 1.2        | V        |
| Diode Forward Current (Note 2)     | Is                  |  | -             | -          | 5          | Α        |
| Forward Turn-On Time               | t <sub>on</sub>     | Intrinsic turn-on time is neg                                    | ligible (turr | n-on is do | ominated b | y LS+LD) |

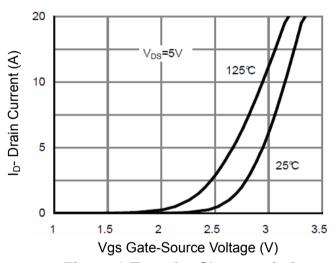
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition:Tj=25 $^{\circ}$ C,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$

## **Typical Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

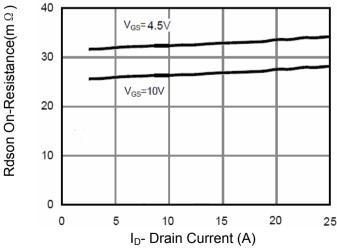
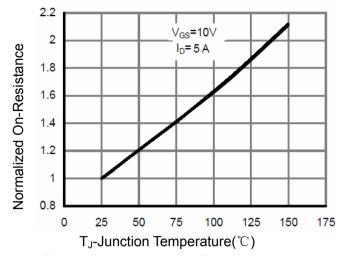
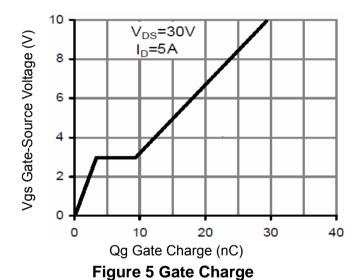


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 



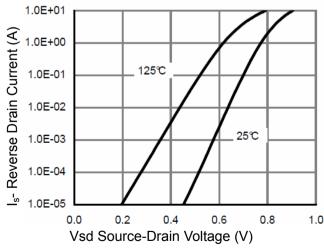


Figure 6 Source- Drain Diode Forward

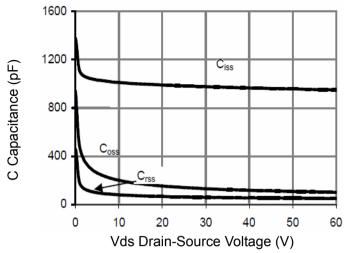
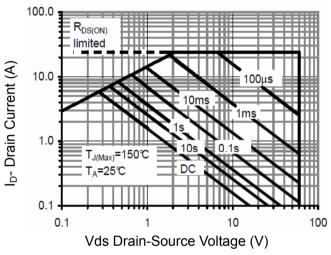


Figure 7 Capacitance vs Vds



**Figure 8 Safe Operation Area** 

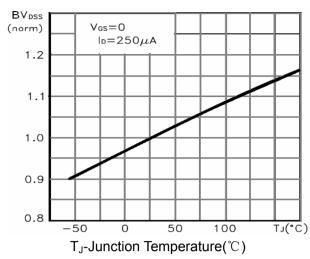


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

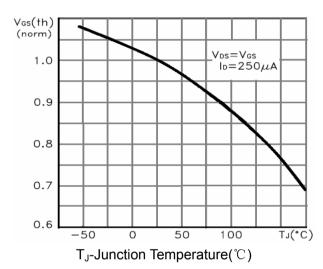
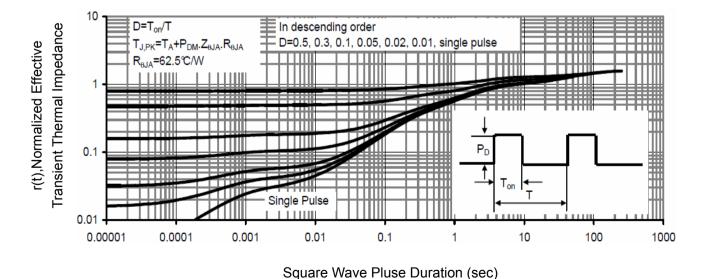


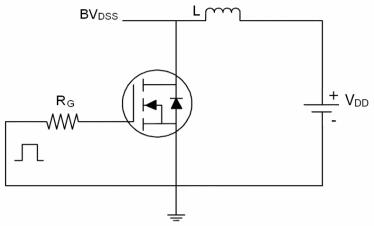
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



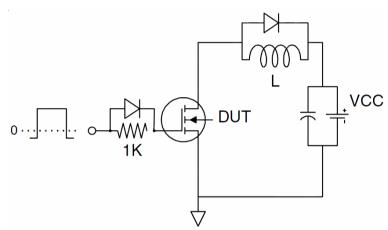
**Figure 11 Normalized Maximum Transient Thermal Impedance** 

## **Test Circuit**

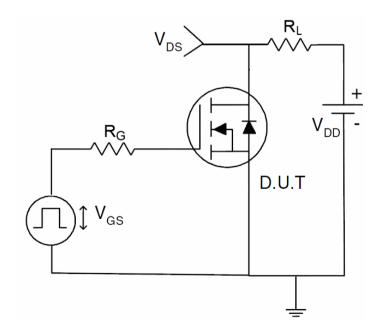
## 1) AS test Circuit



## 2) Gate c rge test Circuit



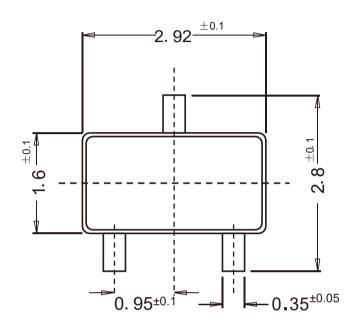
## 3) witch Time Test Circuit

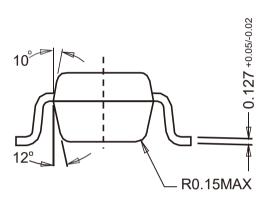


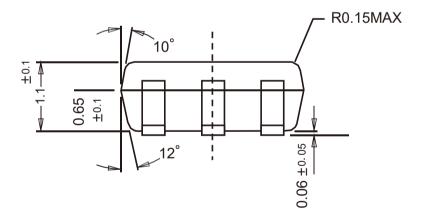
## **Package Outline**

SOT-23-3

Dimensions in mm





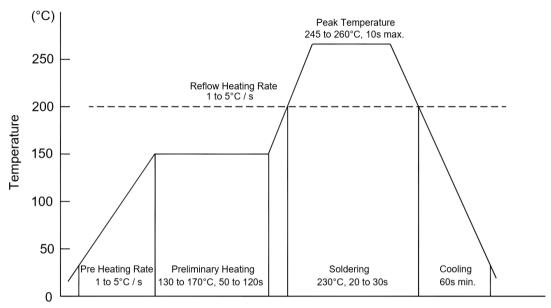


## **Ordering Information**

| Device    | Package  | Shipping              |  |
|-----------|----------|-----------------------|--|
| TN05N60SC | SOT-23-3 | 3,000PCS/Reel&7inches |  |

## **Conditions of Soldering and Storage**

## Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### Conditions of hand soldering

• Temperature: 370 °C

Time: 3s max.Times: one time

### Storage conditions

Temperature

5 to 40 °C

Humidity

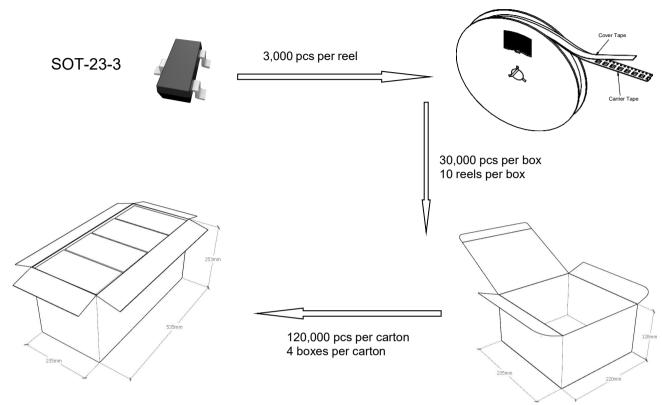
30 to 80% RH

Recommended period

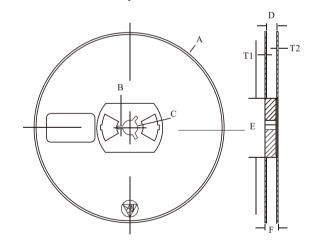
One year after manufacturing

## **Package Specifications**

• The method of packaging

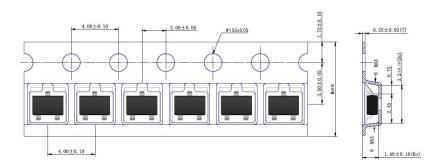


## ♦ Embossed tape and reel data



| Symbol | Value (unit: mm) |  |
|--------|------------------|--|
| Α      | Ø 177.8±1        |  |
| В      | 2.7±0.2          |  |
| С      | Ø 13.5±0.2       |  |
| Е      | Ø 54.5±0.2       |  |
| F      | 12.3±0.3         |  |
| D      | 9.6+2/-0.3       |  |
| T1     | 1.0±0.2          |  |
| T2     | 1.2±0.2          |  |

Reel (7")



#### **Contact Information**

TANI website: http://www.tanisemi.com Email:tani@tanisemi.com

For additional information, please contact your local Sales Representative.



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#### **Product Specification Statement**

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The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also throughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

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Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

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